

# Abstracts

## High-Efficiency AlGaAs/GaAs HBT Power Amplifier MMIC for 1.9GHz Japanese Digital Cordless Phone

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*S. Hara, H. Sato, J.K. Twynam, M. Akagi, N. Nambu, N. Tanba, K. Yoshikawa, T. Kinoshita, M. Yagura, H. Tsuji, T. Shinozaki, T. Yoshimasu, T. Miyajima and T. Tomita. "High-Efficiency AlGaAs/GaAs HBT Power Amplifier MMIC for 1.9GHz Japanese Digital Cordless Phone." 1993 Microwave and Millimeter-Wave Monolithic Circuits Symposium Digest 93.1 (1993 [MCS]): 19-22.*

An AlGaAs/GaAs HBT power amplifier MMIC for 1.9 GHz Japanese digital cordless phone applications is demonstrated. A P/sub 1dB/ of 24 dBm and a P/sub 1dB/ power added efficiency as high as 40 % are achieved at voltage of only 3 V. This is the highest power added efficiency ever reported for such an amplifier operating at any voltage.

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